

# SB515SVF - SB530SVF

# SCHOTTKY BARRIER RECTIFIER DIODES

**PRV : 15 - 30 Volts**

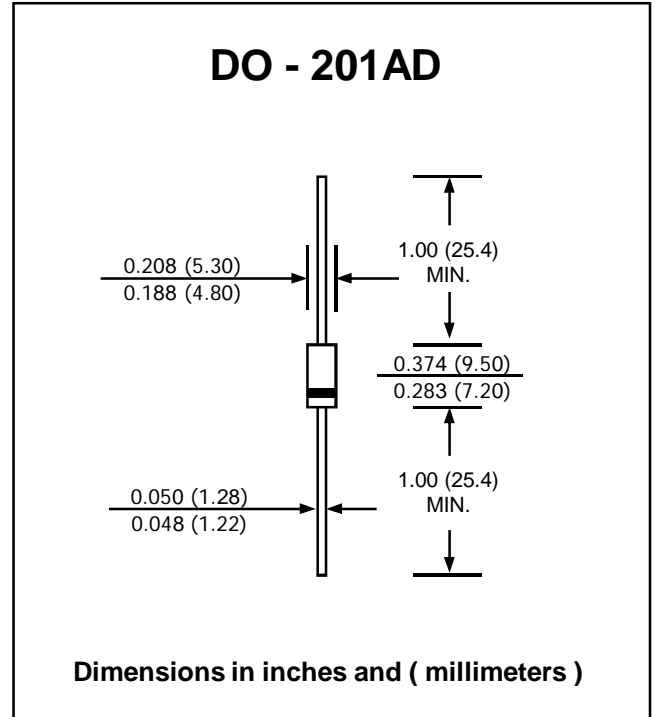
**I<sub>o</sub> : 5.0 Amperes**

**FEATURES :**

- \* High current capability
- \* High surge current capability
- \* High reliability
- \* High efficiency
- \* Low power loss
- \* Low cost
- \* Low forward voltage drop
- \* Pb / RoHS Free

**MECHANICAL DATA :**

- \* Case : DO-201AD Molded plastic
- \* Epoxy : UL94V-O rate flame retardant
- \* Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- \* Polarity : Color band denotes cathode end
- \* Mounting position : Any
- \* Weight : 1.16 grams



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

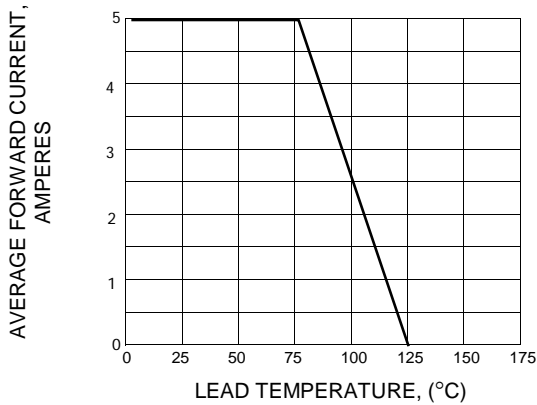
RATING	SYMBOL	SB515SVF	SB530SVF	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	15	30	V
Maximum RMS Voltage	V <sub>RMS</sub>	11	21	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	15	30	V
Maximum Average Forward Current 0.375", 9.5mm Lead Length See Fig.1	I <sub>F(AV)</sub>	5.0		A
Maximum Peak Forward Surge Current, 8.3ms single half sine wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	150		A
Maximum Forward Voltage at I <sub>F</sub> = 5 A (Note 1)	V <sub>F</sub>	0.39	0.40	V
Maximum Reverse Current at Ta = 25 °C Rated DC Blocking Voltage (Note 1) Ta = 100 °C	I <sub>R</sub>	0.5		mA
	I <sub>R(H)</sub>	50		mA
Junction Temperature Range	T <sub>J</sub>	- 65 to + 125		°C
Storage Temperature Range	T <sub>STG</sub>	- 65 to + 150		°C

**Notes :**

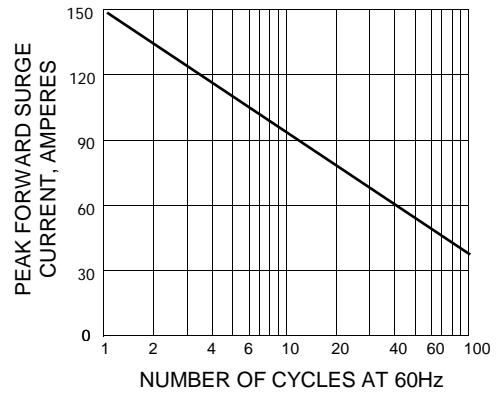
(1) Pulse Test : Pulse Width = 300 μs, Duty Cycle = 2%.

**RATING AND CHARACTERISTIC CURVES ( SB515SVF - SB530SVF )**

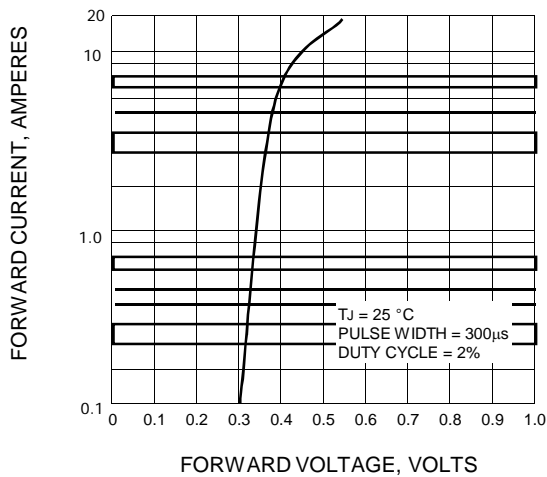
**FIG.1 - FORWARD CURRENT DERATING CURVE**



**FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.3 - TYPICAL FORWARD CHARACTERISTICS**



**FIG.4 - TYPICAL REVERSE CHARACTERISTICS**

